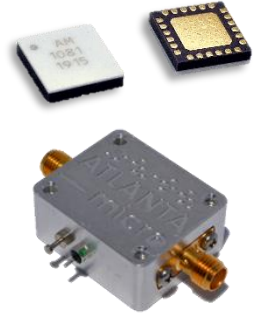


AM1081 – Amplifier

DC to 8 GHz Bypassable

Description

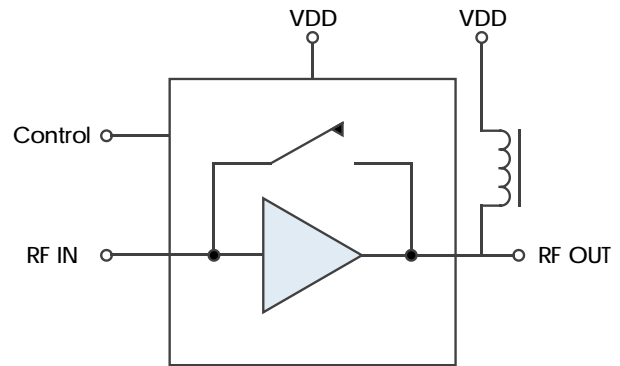
The AM1081 is a high dynamic range bypassable DC-coupled amplifier covering up to 8 GHz. The device exhibits low bypass insertion loss and a moderate positive gain-slope, providing frequency equalization useful in many broadband applications. Packaged in a 4mm QFN or a shielded module with internal 50Ω matching and requiring a single positive control voltage, the AM1081 represents a dramatic size reduction over a discrete implementation of a bypassable amplifier.



Features

- 17 dB Gain
- 2.5 dB Noise Figure
- +35 dBm OIP3
- +20 dBm P1dB
- +20 dBm PSat
- 1.25 dB Bypass Insertion Loss
- +5.0V, 83/1 mA (Gain/Bypass)
- +3.0V to +5.0V Supply Range
- +3.3V or +5V Logic Compatible
- 4mm QFN Package

Functional Diagram



Characteristic Performance

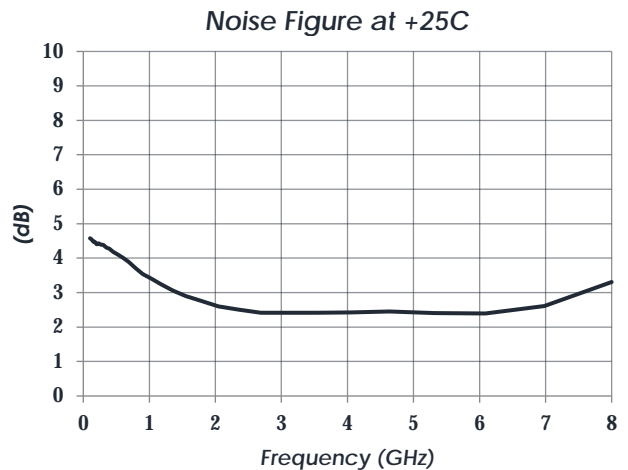
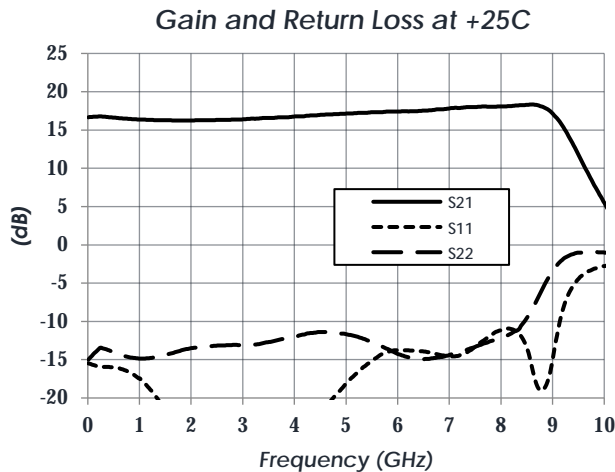


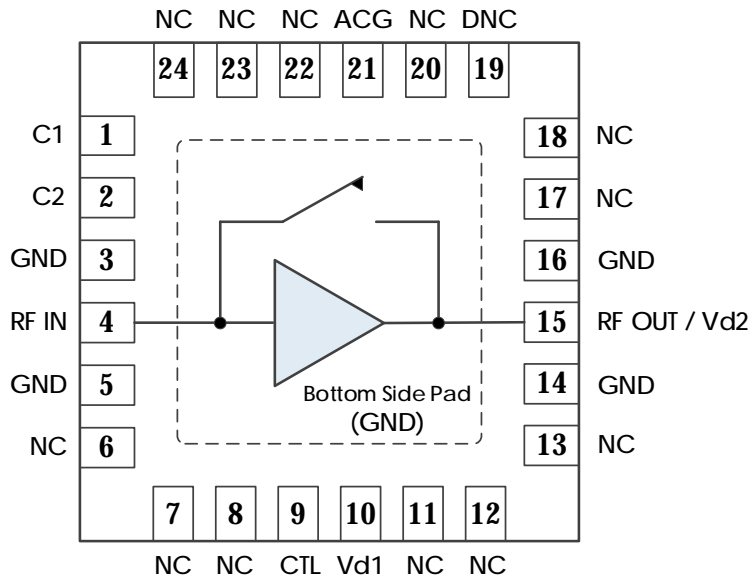
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Revision History

Date	Revision Number	Notes
May 8, 2019	1	Initial Release
June 6, 2019	1A	Component Compliance Information Updated
November 25, 2019	2	RF-Shielded Module Information Added, Part Ordering Details Added
February 5, 2020	3	Added correct module RF I/O labels
May 8, 2020	4	Changed pin 19 to DNC instead of GND for correct performance. Moved package and module information to main product page.
October 7, 2020	5	Control pin current drive level added.

Pin Layout and Definitions



Pin Number	Pin Name	Pin Function
1	C1	External Capacitor Connection 1
2	C2	External Capacitor Connection 2
3	GND	Ground – Common
4	RF IN	RF Input – 50 ohms – DC Coupled, External DC Block Required
5	GND	Ground – Common
6-8	NC	Not Connected *
9	CTL	Bypass/Amplifier Mode Control
10	VD1	DC Power Input
11-13	NC	Not Connected *
14	GND	Ground – Common
15	RF OUT/VD2	RF Output and DC Power Input – 50 Ohms – DC Coupled, External DC Block Required.
16	GND	Ground – Common
17, 18	NC	Not Connected *
19	DNC	Do Not Connect (leave floating)
20	NC	Not Connected *
21	ACG	AC Ground
22-24	NC	Not Connected *
Case GND	GND	Ground – Common

*NC pins may be grounded or left open

AM1081 – Amplifier



DC to 8 GHz Bypassable

Specifications

Absolute Maximum Ratings

	Minimum	Maximum
Supply Voltage	0.0 V	+6.0 V
RF Input Power		+20 dBm
Operating Junction Temperature	-40 C	+150 C
Storage Temperature Range	-50C	+150 C

Note: Any device operation beyond the Absolute Maximum Ratings may result in permanent damage to the device. The values listed in this table are extremes and do not imply functional operation of the device at these or any other conditions beyond what is listed under Recommended Operating Conditions. Any part subjected to conditions outside of what is recommended for an extended amount of time may suffer from reliability concerns.

Handling Information

	Minimum	Maximum
Storage Temperature Range (Recommended)	-50 C	+125 C
Moisture Sensitivity Level	MSL 3	



Atlanta Micro products are electrostatic sensitive.
Follow safe handling practices to avoid damage

Recommended Operating Conditions

	Minimum	Typical	Maximum
Supply Voltage	+3.0 V	+5.0 V	+5.2 V
Operating Case Temperature	-40 C		+85 C
Operating Junction Temperature	-40 C		+125 C

Thermal Information

	Thermal Resistance (°C / W)
Junction to Case Thermal Resistance (θ_{JC})	49.5

AM1081 – Amplifier

DC to 8 GHz Bypassable

DC Electrical Characteristics

(T = 25 °C unless otherwise specified)

Parameter	Testing Conditions	Minimum	Typical	Maximum
DC Supply Voltage		+3.0 V	+5.0 V	+5.2 V
DC Supply Current	VDD = +5.0 V		83 mA	
	VDD = +3.3 V		52 mA	
Power Dissipated	VDD = +5.0 V		0.42 W	
	VDD = +3.3 V		0.17 W	
Logic Level Low		-0.1 V		+0.4 V
Logic Level High		+2.2 V		+5.0 V
Control Current	CTL = +3.3V		115 μ A	
	CTL = +5.0V		200 μ A	

RF Performance

(T = 25 °C, VDD = +5.0 V unless otherwise specified)

Parameter	Testing Conditions	Minimum	Typical	Maximum
Frequency Range		DC		8 GHz
Gain	VDD = +5.0 V		17.0 dB	
	VDD = +3.3 V		16.5 dB	
Return Loss	VDD = +5.0 V		15 dB	
Bypass Insertion Loss	VDD = +5.0 V		1.25 dB	
Output IP3	VDD = +5.0 V		+35 dBm	
Output P1dB	VDD = +5.0 V		+20 dBm	
Noise Figure	VDD = +5.0 V		2.5 dB	

State Table

CTL	Amplifier
High	Enabled
Low	Bypassed

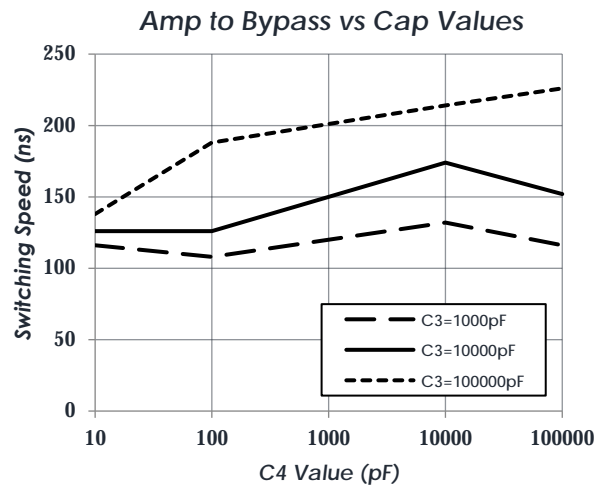
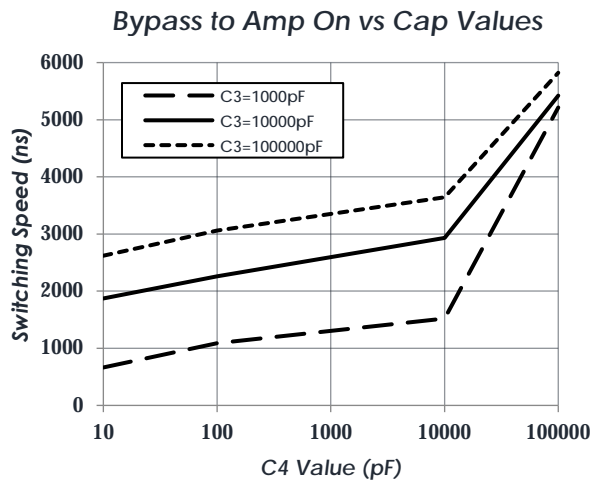
AM1081 – Amplifier

DC to 8 GHz Bypassable

Timing Characteristics

(T = 25 °C, VDD = +3.3V, CTL = 0.0V / +3.3V)

Switching Time	Minimum	Typical ²	Maximum
Amp On → Amp Bypass	125 ns	175 ns	300 ns
Amp Bypass → Amp On	700 ns	3.8 μs	7.0 μs



***Notes:**

1. Switching speeds measured as 50% trigger to 10%/90% RF respectively.
2. Typical measurements reflect switching speeds of amp as configured in Typical Application section.
3. To change times, alter value of C3 and C4 (see Typical Application section).

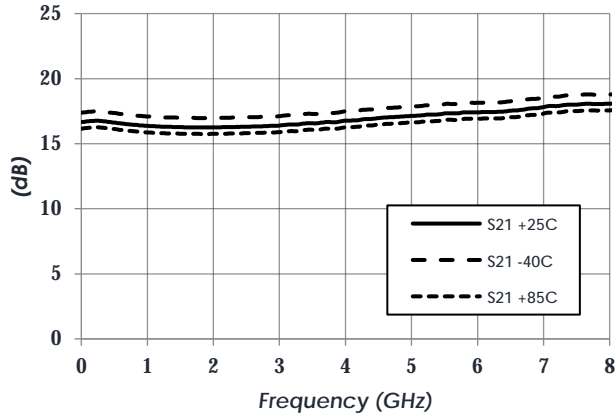
AM1081 – Amplifier

DC to 8 GHz Bypassable

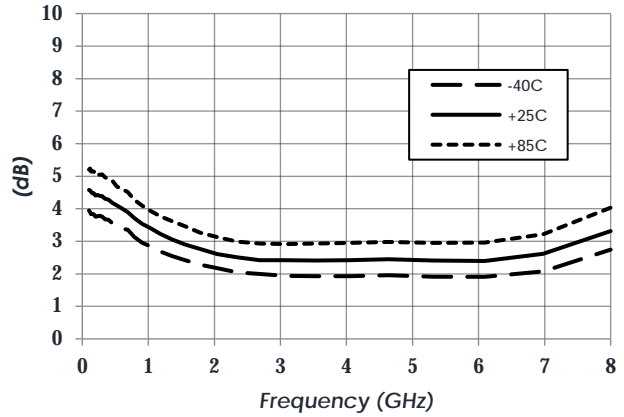
Typical Performance

(Amplifier Enabled, VDD = +5.0 V, ID = 83 mA)

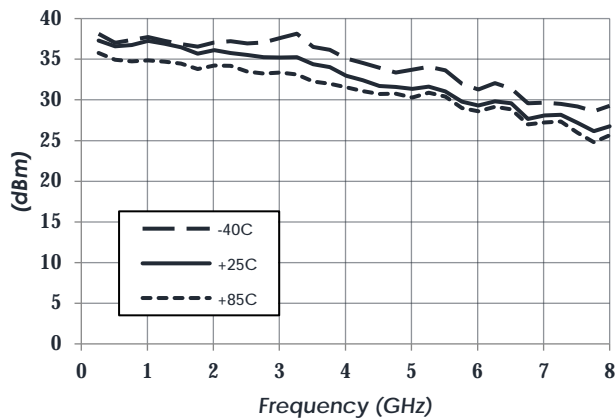
Gain vs Temperature



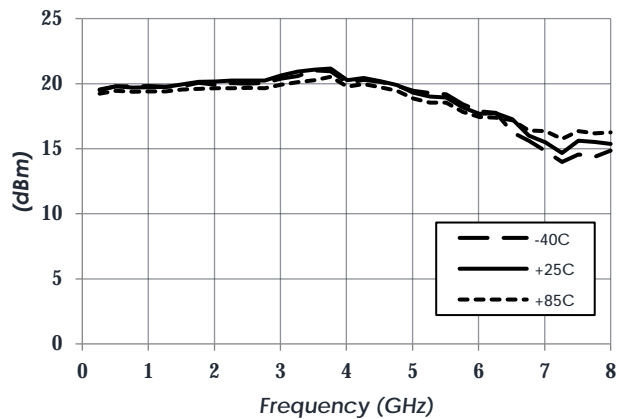
Noise Figure vs Temperature



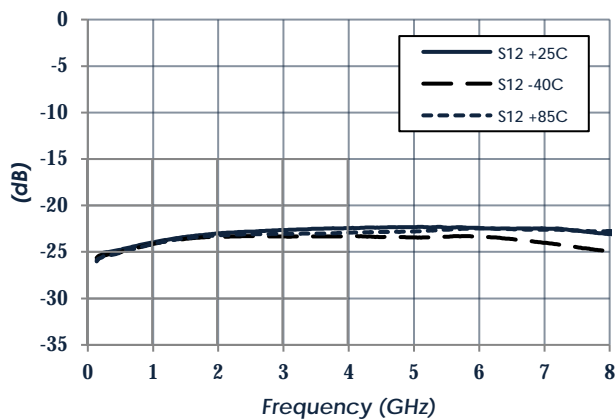
Output IP3 vs Temperature



P1dB vs Temperature



Reverse Isolation vs Temperature

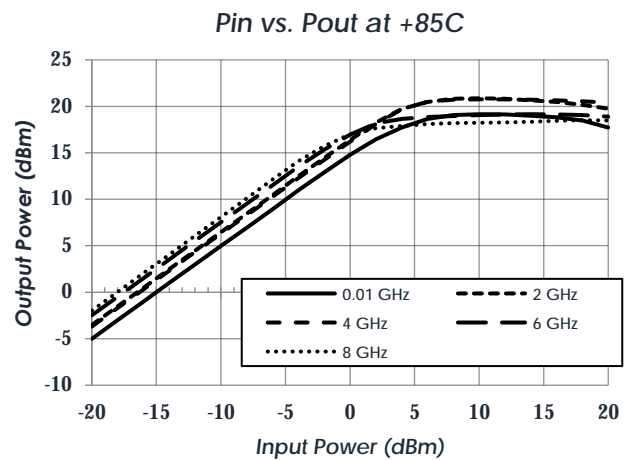
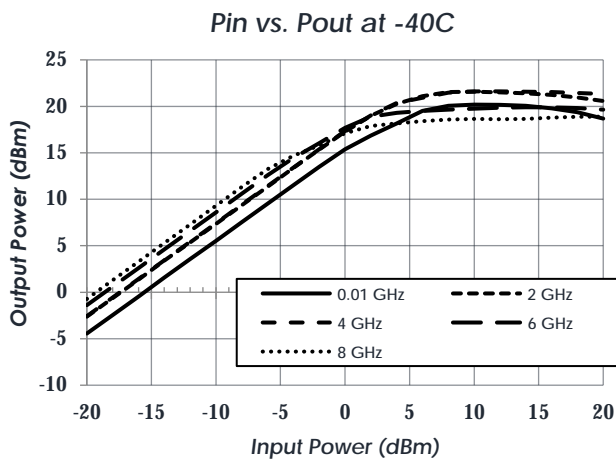
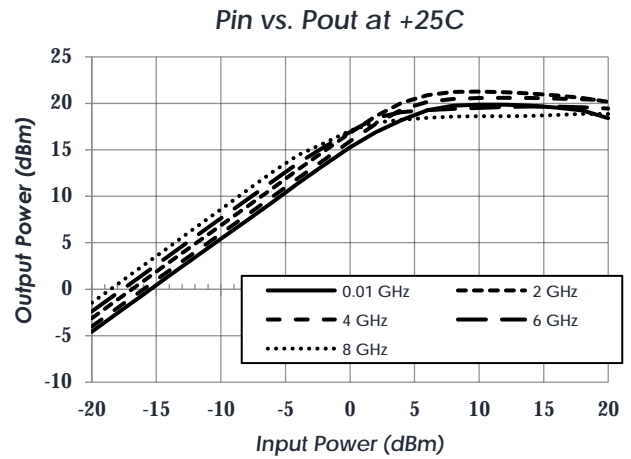
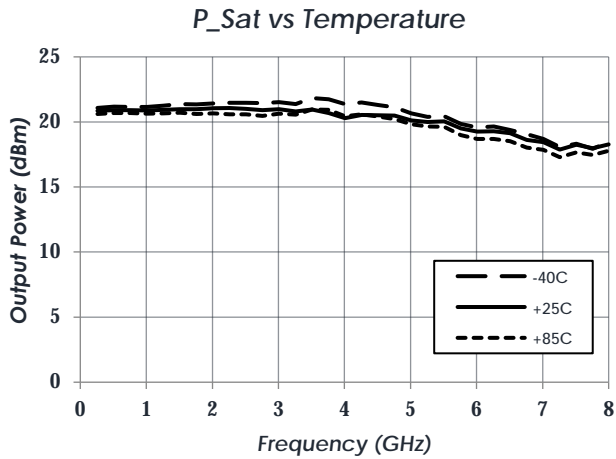


AM1081 – Amplifier

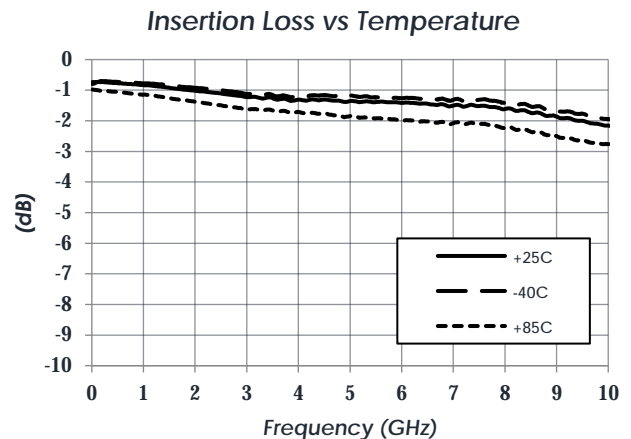
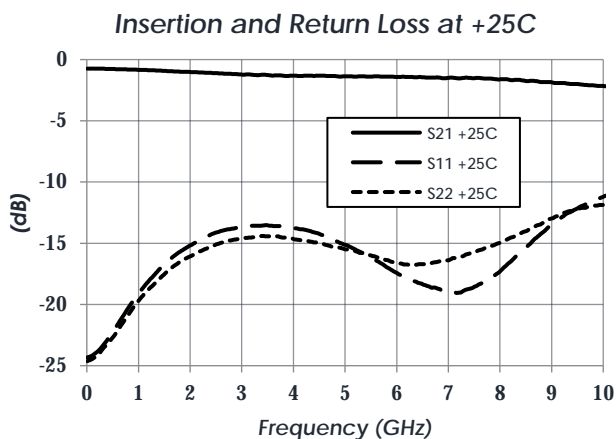
DC to 8 GHz Bypassable

Typical Performance (continued)

(Amplifier Enabled, VDD = +5.0 V, ID = 83 mA)



(Amplifier Bypass, VDD = +5.0 V, ID = 1mA)



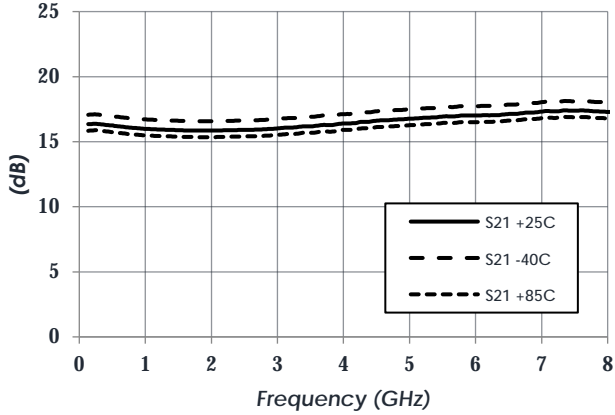
AM1081 – Amplifier

DC to 8 GHz Bypassable

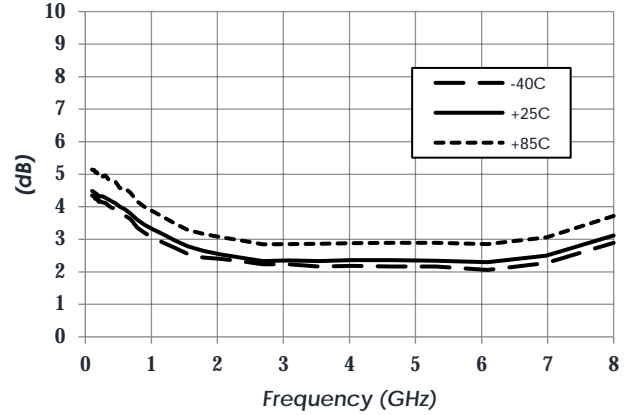
Typical Performance (continued)

(Amplifier Enabled, VDD = +3.3 V, ID = 52 mA)

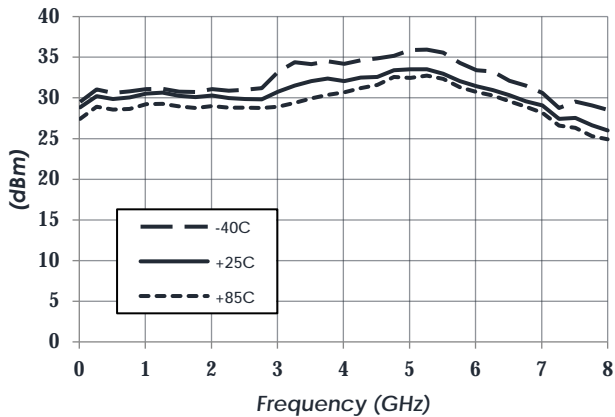
Gain vs Temperature



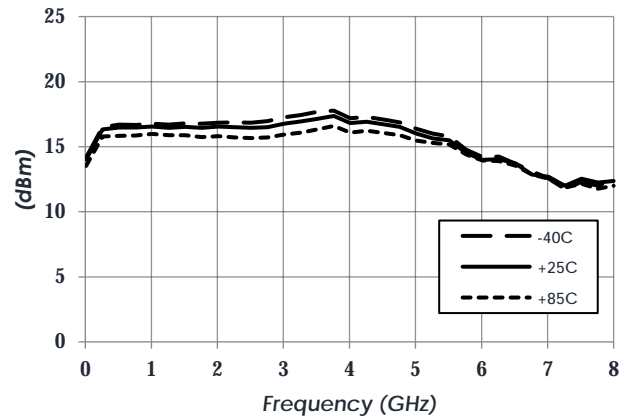
Noise Figure vs Temperature



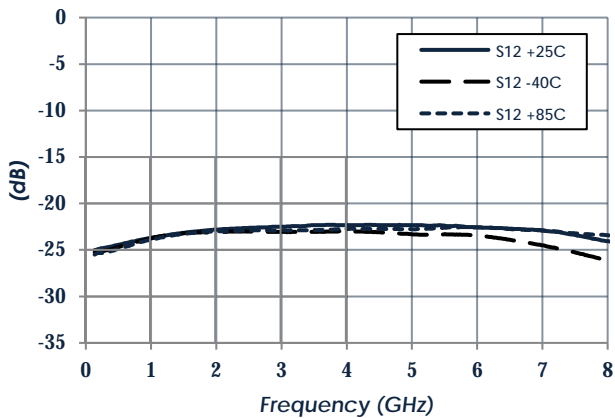
Output IP3 vs Temperature



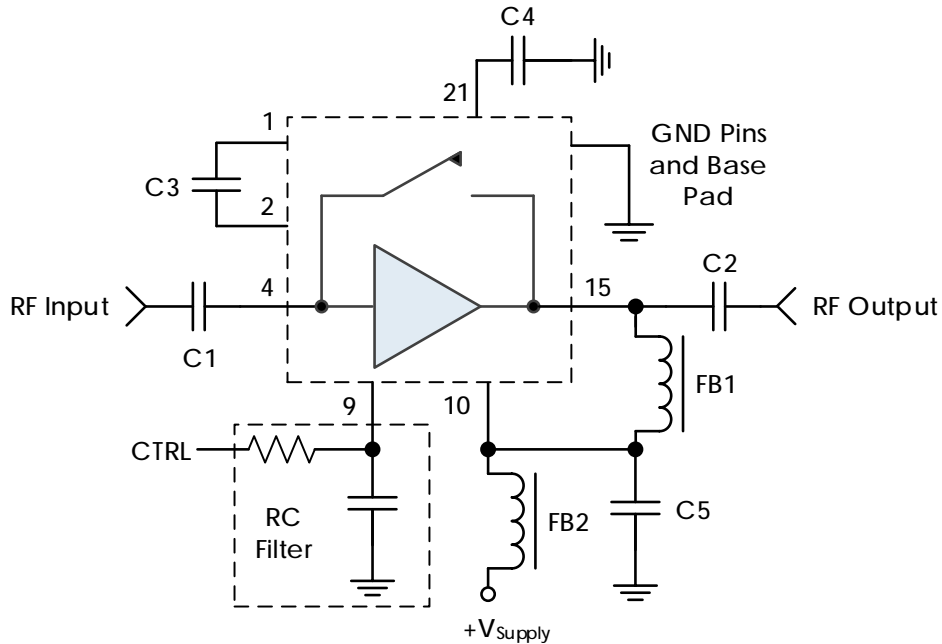
P1dB vs Temperature



Reverse Isolation vs Temperature



Typical Application



Recommended Component List (or equivalent):

Part	Value	Part Number	Manufacturer
C1, C2	0.1 μ F	0402BB104KW500	Passives Plus
C3	0.1 μ F	0201BB104KW250	Passives Plus
C4	10,000 pF	GRM033R61E103KA12D	Murata
C5	0.1 μ F	GCM155R71H104KE02J	Murata
FB1, FB2	-	MMZ1005A222E	TDK

Notes:

1. DC blocking capacitors C1 – C3 should be high performance, low-loss, broadband capacitors for optimum performance.
2. Select control line RC filter values based on desired logic source decoupling and switching speed
3. C3 and C4 should be placed as close to the AM1081 as possible to minimize PCB trace lengths. A 0201 package size is recommended to minimize stray PCB pad capacitance to ground.

AM1081 – Amplifier

DC to 8 GHz Bypassable

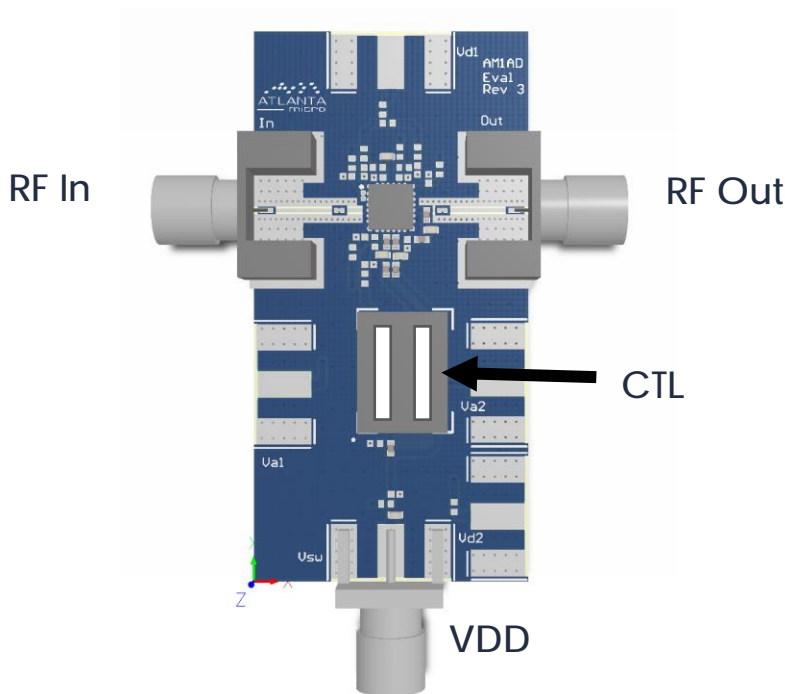
Part Ordering Details

Description	Part Number
4mm 24 Lead QFN	AM1081
AM1081 Evaluation Board	AM1081 Eval
AM1081 in 0.95" x 1.13" x 0.6" RF-Shielded Module with Integrated Bias Tee and Field Replaceable SMA Connectors	AM1081-M

Related Parts

Part Number	Description
AM1031C	20 MHz to 8 GHz +3.3V Gain Block
AM1063-1	DC to 10 GHz Gain Block
AM1063-2	DC to 10 GHz Miniature Gain Block
AM1064-1	DC to 8 GHz Gain Block
AM1064-2	DC to 8 GHz Miniature Gain Block
AM1065	DC to 8 GHz Bypassable Gain Block
AM1067	5 GHz to 20 GHz Bypassable Gain Block
AM1073	DC to 8 GHz Bidirectional / Bypassable Gain Block
AM1075	5 GHz to 26.5 GHz Bypassable Gain Block
AM1077	5 GHz to 20 GHz Bypassable Gain Block w/ Isolation State

Evaluation PC Board



To obtain price, delivery, or to place an order contact MMICSales@rcy.com
 Atlanta Micro Inc., 3720 Davinci Ct, Suite 125, Peachtree Corners, GA 30092 • Phone: (470) 253-7640 • www.atlantamicro.com

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Substance List	Allowable Maximum Concentration
Lead (Pb)	<1000 PPM (0.1% by weight)
Mercury (Hg)	<1000 PPM (0.1% by weight)
Cadmium (Cd)	<75 PPM (0.0075% by weight)
Hexavalent Chromium (CrVI)	<1000 PPM (0.1% by weight)
Polybrominated Biphenyls (PBB)	<1000 PPM (0.1% by weight)
Polybrominated Diphenyl ethers (PBDE)	<1000 PPM (0.1% by weight)
Decabromodiphenyl Deca BDE	<1000 PPM (0.1% by weight)
Bis (2-ethylhexyl) Phthalate (DEHP)	<1000 PPM (0.1% by weight)
Butyl Benzyl Phthalate (BBP)	<1000 PPM (0.1% by weight)
Dibutyl Phthalate (DBP)	<1000 PPM (0.1% by weight)
Diisobutyl Phthalate (DIBP)	<1000 PPM (0.1% by weight)

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